![Chipsmall logo]

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from,Europe,America and south Asia,supplying obsolete and hard-to-find components to meet their specific needs.

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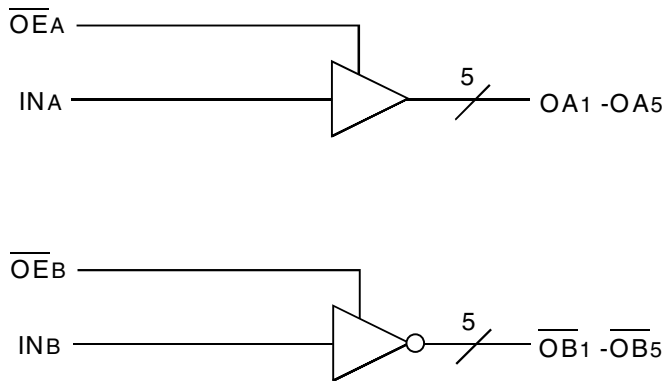
FAST CMOS
BUFFER/CLOCK DRIVER

IDT74FCT810BT/CT

FEATURES:

- **0.5 MICRON CMOS Technology**
- **Guaranteed low skew < 600ps (max.)**
- **Very low duty cycle distortion < 700ps (max.)**
- **Low CMOS levels**
- **TTL compatible inputs and outputs**
- **TTL level output voltage swings**
- **High drive: -32mA I_{OH}, +48mA I_{OL}**
- **Two independent output banks with 3-state control:**
  - *One 1:5 inverting bank*
  - *One 1:5 non-inverting bank*
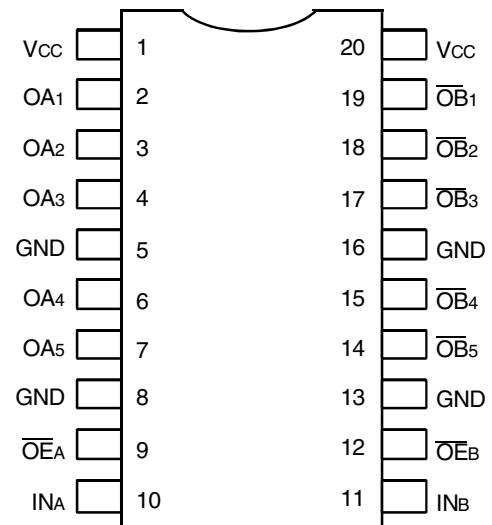- **Available in QSOP, SSOP, and SOIC packages**

DESCRIPTION:

The 74FCT810T is a dual bank inverting/ non-inverting clock driver built using advanced dual metal CMOS technology. It consists of two banks of drivers, one inverting and one non-inverting. Each bank drives five output buffers from a standard TTL-compatible input. The FCT810T has low output skew, pulse skew and package skew. Inputs are designed with hysteresis circuitry for improved noise immunity. The outputs are designed with TTL output levels and controlled edge rates to reduce signal noise. The part has multiple grounds, minimizing the effects of ground inductance.

FUNCTIONAL BLOCK DIAGRAM

PIN CONFIGURATION

QSOP/ SOIC/ SSOP
TOP VIEW

COMMERCIAL TEMPERATURE RANGE

MAY 2010

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DSC-4646/3

ABSOLUTE MAXIMUM RATINGS[1]

Symbol	Description	Max	Unit
V_{TERM}	Terminal Voltage with Respect to GND	−0.5 to +7	V
T_{STG}	Storage Temperature	−65 to +150	°C
I_{OUT}	DC Output Current	−60 to +120	mA

NOTE:
1. Stresses greater than those listed under ABSOLUTE MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.

CAPACITANCE (T_A = +25°C, f = 1.0MHz)

Symbol	Parameter[1]	Conditions	Typ.	Max.	Unit
C_{IN}	Input Capacitance	V_{IN} = 0V	4.5	6	pF
C_{OUT}	Output Capacitance	V_{OUT} = 0V	5.5	8	pF

NOTE:
1. This parameter is measured at characterization but not tested.

PIN DESCRIPTION

Pin Names	Description
$\overline{OE}_A$, $\overline{OE}_B$	3-State Output-Enable Inputs (Active LOW)
IN_A, IN_B	Clock Inputs
OA_X, OB_X	Clock Outputs

DC ELECTRICAL CHARACTERISTICS OVER OPERATING RANGE

Following Conditions Apply Unless Otherwise Specified:
Commercial: T_A = 0°C to +70°C, V_{CC} = 5V ± 5%

Symbol	Parameter	Test Conditions[1]		Min.	Typ.[2]	Max.	Unit
V_{IH}	Input HIGH Level (Input pins)	Guaranteed Logic HIGH Level		2	—	—	V
V_{IL}	Input LOW Level	Guaranteed Logic LOW Level		—	—	0.8	V
I_{IH}	Input HIGH Current (Input pins)	V_{CC} = Max.	V_I = 2.7V	—	—	±1	μA
I_{IL}	Input LOW Current (Input pins)	V_{CC} = Max.	V_I = 0.5V	—	—	±1	μA
I_{OZH}	High Impedance Output Current	V_{CC} = Max.	V_O = 2.7V	—	—	±1	μA
I_{OZL}	(3-State Output pins)		V_O = 0.5V	—	—	±1	
I_I	Input HIGH Current	V_{CC} = Max., V_I = V_{CC} (Max.)		—	—	±1	μA
V_{IK}	Clamp Diode Voltage	V_{CC} = Min., I_{IN} = −18mA		—	−0.7	−1.2	V
I_{OS}	Short Circuit Current	V_{CC} = Max., V_O = GND[3]		−60	−120	−225	mA
V_{OH}	Output HIGH Voltage	V_{CC} = Min.	I_{OH} = −15mA	2.4	3.3	—	V
		V_{IN} = V_{IH} or V_{IL}	I_{OH} = −32mA[4]	2	3	—	
V_{OL}	Output LOW Voltage	V_{CC} = Min.	I_{OL} = 48mA	—	0.3	0.55	V
		V_{IN} = V_{IH} or V_{IL}					
I_{OFF}	Input/Output Power Off Leakage	V_{CC} = 0V, V_{IN} or V_O ≤4.5V		—	—	±1	μA
V_H	Input Hysteresis for all inputs	—		—	150	—	mV
I_{CCL} I_{CCH} I_{CCZ}	Quiescent Power Supply Current	V_{CC} = Max., V_{IN} = GND or V_{CC}		—	5	500	μA

NOTES:
1. For conditions shown as Max. or Min., use appropriate value specified under Electrical Characteristics for the applicable device type.
2. Typical values are at Vcc = 5V, +25°C ambient.
3. Not more than one output should be shorted at one time. Duration of the test should not exceed one second.
4. Duration of the condition should not exceed one second.

POWER SUPPLY CHARACTERISTICS

Symbol	Parameter	Test Conditions[1]		Min.	Typ.[2]	Max.	Unit
ΔI_{CC}	Quiescent Power Supply Current TTL Inputs HIGH	V_{CC} = Max. V_{IN} = 3.4V[3]		—	0.5	2	mA
I_{CCD}	Dynamic Power Supply Current[4]	V_{CC} = Max. Outputs Open $\overline{OE}_A$ = $\overline{OE}_B$ = GND 50% Duty Cycle	V_{IN} = V_{CC} V_{IN} = GND	—	60	100	μA/MHz
I_C	Total Power Supply Current[6]	V_{CC} = Max. Outputs Open f_O = 25MHz	V_{IN} = V_{CC} V_{IN} = GND	—	7.5	13	mA
		50% Duty Cycle $\overline{OE}_A$ = GND, $\overline{OE}_B$ = V_{CC}	V_{IN} = 3.4V V_{IN} = GND	—	7.8	14	
		V_{CC} = Max. Outputs Open f_O = 50MHz	V_{IN} = V_{CC} V_{IN} = GND	—	30	50.5[5]	
		50% Duty Cycle $\overline{OE}_A$ = $\overline{OE}_B$ = GND	V_{IN} = 3.4V V_{IN} = GND	—	30.5	52.5[5]	

NOTES:

1. For conditions shown as Max. or Min., use appropriate value specified under Electrical Characteristics for the applicable device type.
2. Typical values are at V_{CC} = 5V, +25°C ambient.
3. Per TTL driven input (V_{IN} = 3.4V); all other inputs at V_{CC} or GND.
4. This parameter is not directly testable, but is derived for use in Total Power Supply calculations.
5. Values for these conditions are examples of the I_C formula. These limits are guaranteed but not tested.
6. $I_C = I_{QUIESCENT} + I_{INPUTS} + I_{DYNAMIC}$

   $I_C = I_{CC} + \Delta I_{CC} D_H N_T + I_{CCD} (f_O N_O)$

   I_{CC} = Quiescent Current (I_{CCL}, I_{CCH} and I_{CCZ})

   ΔI_{CC} = Power Supply Current for a TTL High Input (V_{IN} = 3.4V)

   D_H = Duty Cycle for TTL Inputs High

   N_T = Number of TTL Inputs at D_H

   I_{CCD} = Dynamic Current Caused by an Input Transition Pair (HLH or LHL)

   f_O = Output Frequency

   N_O = Number of Outputs at f_O

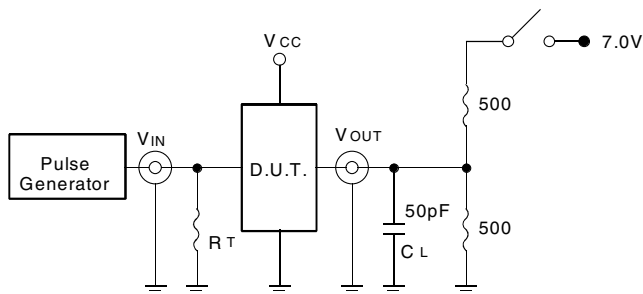   All currents are in milliamps and all frequencies are in megahertz.

SWITCHING CHARACTERISTICS OVER OPERATING RANGE[3,4]

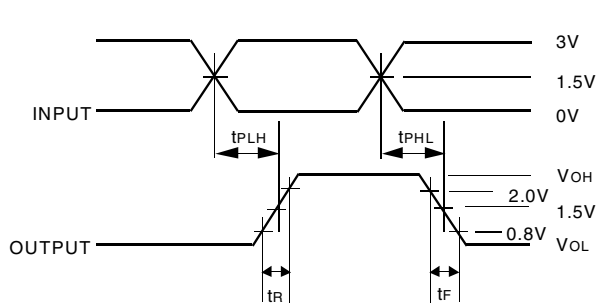| Symbol	Parameter	Conditions[1]	FCT810BT		FCT810CT		Unit
			Min.[2]	Max.	Min.[2]	Max.	
t_{PLH} t_{PHL}	Propagation Delay INA to OAx, INA to OBx	$C_L = 50pF$ $R_L = 500\Omega$	1.5	4.5	1.5	4.3	ns
t_R	Output Rise Time		—	1.5	—	1.5	ns
t_F	Output Fall Time		—	1.5	—	1.5	ns
$t_{SK1(O)}$	Output skew (same bank): skew between outputs of same bank and same package (same transition)		—	0.5	—	0.3	ns
$t_{SK2(O)}$	Output skew (all banks): skew between outputs of all banks of same package (inputs tied together)		—	0.7	—	0.6	ns
$t_{SK(P)}$	Pulse skew: skew between opposite transitions of same output ($|t_{PHL} - t_{PLH}|$)		—	0.7	—	0.7	ns
$t_{SK(T)}$	Package skew: skew between outputs of different packages at same power supply voltage, temperature, package type and speed grade		—	1.2	—	1	ns
t_{PZL} t_{PZH}	Output Enable Time OEA to OAx, OEB to OBx		1.5	6	1.5	5	ns
t_{PLZ} t_{PHZ}	Output Disable Time OEA to OAx, OEB to OBx		1.5	6	1.5	5	ns

NOTES:
1. See test circuits and waveforms.
2. Minimum limits are guaranteed but not tested on Propagation Delays.
3. t_{PLH}, t_{PHL}, $t_{SK}(t)$ are production tested. All other parameters guaranteed but not production tested.
4. Propagation delay range indicated by Min. and Max. limit is due to V_{CC}, operating temperature and process parameters. These propagation delay limits do not imply skew.
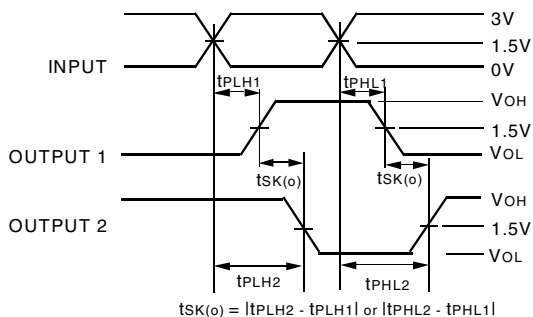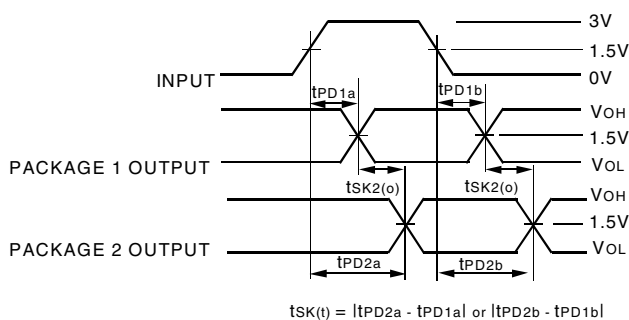
TEST CIRCUITS AND WAVEFORMS

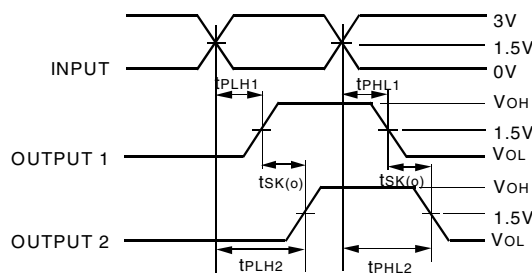*Test Circuit for All Outputs*

Package Delay

$t_{SK(o)} = |t_{PLH2} - t_{PLH1}|$ or $|t_{PHL2} - t_{PHL1}|$

Output Skew (All Banks) - $t_{SK2(O)}$

$t_{SK(t)} = |t_{PD2a} - t_{PD1a}|$ or $|t_{PD2b} - t_{PD1b}|$

Package Skew - $t_{SK(T)}$

NOTES:
1. Diagram shown for input Control Enable-LOW and input Control Disable-HIGH
2. Pulse Generator for All Pulses: Rate ≤1.0MHz; t_F ≤2.5ns; t_R ≤2.5ns

SWITCH POSITION

Test	Switch
Disable LOW Enable LOW	Closed
Disable HIGH Enable HIGH	GND

DEFINITIONS:

C_L = Load capacitance: includes jig and probe capacitance.

R_T = Termination resistance: should be equal to Z_{OUT} of the Pulse Generator.

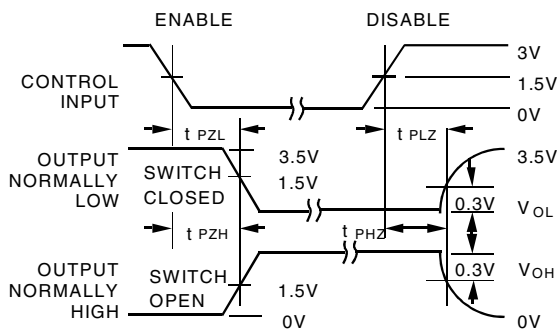$t_{SK(o)} = |t_{PLH2} - t_{PLH1}|$ or $|t_{PHL2} - t_{PHL1}|$

Output Skew (Same Bank) - $t_{SK1(O)}$

$t_{SK(p)} = |t_{PHL} - t_{PLH}|$

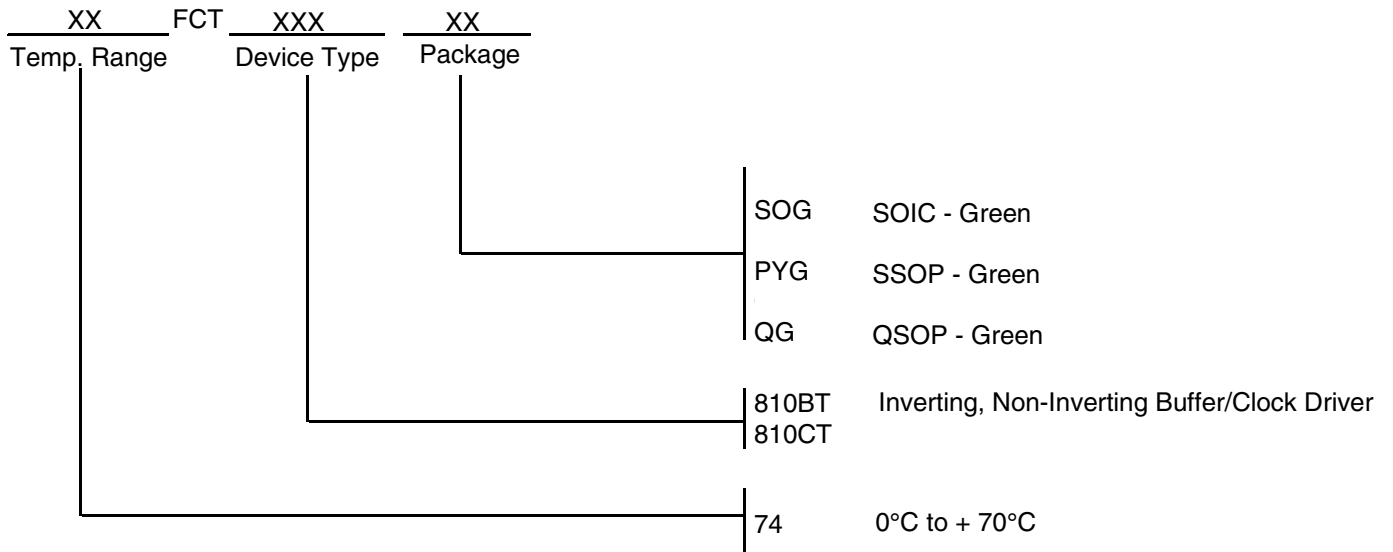*Pulse Skew - $t_{SK(P)}$*

Enable and Disable Times

NOTE:
1. Package 1 and Package 2 are same device type and speed grade.

ORDERING INFORMATION

XX   FCT   XXX   XX
Temp. Range   Device Type   Package

SOG	SOIC - Green
PYG	SSOP - Green
QG	QSOP - Green
810BT	Inverting, Non-Inverting Buffer/Clock Driver
810CT	
74	0°C to + 70°C